NSN 5961-00-754-5308

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Inclosure Material:

Metal

Overall Length:

0.995 inches

Overall Diameter:

0.635 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Thread Size:

0.164 inches

Semiconductor Material:

Germanium

Voltage Rating In Volts Per Characteristic:

28.0 emitter to base voltage, static, collector open and 80.0 collector to base voltage/static/emitter open and 60.0 collector to emitter voltage, dc

Current Rating Per Characteristic:

5.00 amperes source cutoff current and 0.50 amperes source cutoff current

Power Rating Per Characteristic:

34.0 watts small-signal input power, common-collector preset

Special Features:

Junction pattern arrangement: pnp

Thread Series Designator:

Unc

Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0